MENTS LOW-POWER SINGLE POSITIVE-EDGE-TRIGGERED D-TYPE FLIP-FLOP

SCES592D-JULY 2004-REVISED DECEMBER 2007

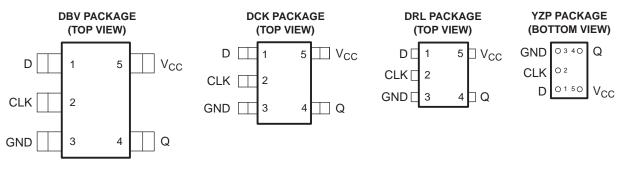
74AUP1G79

FEATURES

www.ti.com

- Available in the Texas Instruments NanoFree™ Package
- Low Static-Power Consumption; I_{CC} = 0.9 μA Max
- Low Dynamic-Power Consumption; C_{pd} = 3 pF Typ at 3.3 V
- Low Input Capacitance; C_i = 1.5 pF Typ
- Low Noise Overshoot and Undershoot <10% of V_{CC}
- Ioff Supports Partial Power-Down-Mode
 Operation
- Input Hysteresis Allows Slow Input Transition and Better Switching Noise Immunity at the Input (V_{hys} = 250 mV Typ at 3.3 V)

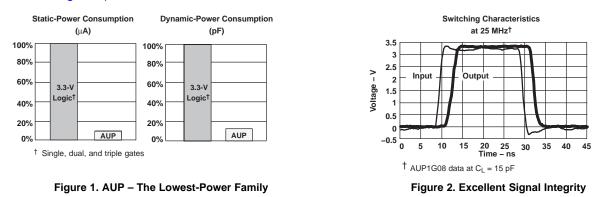
- Wide Operating V_{CC} Range of 0.8 V to 3.6 V
- Optimized for 3.3-V Operation
- 3.6-V I/O Tolerant to Support Mixed-Mode Signal Operation
- t_{pd} = 3.6 ns Max at 3.3 V
- Suitable for Point-to-Point Applications
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Performance Tested Per JESD 22
 - 2000-V Human-Body Model (A114-B, Class II)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)
- ESD Protection Exceeds ±5000 V With Human-Body Model



See mechanical drawings for dimensions.

DESCRIPTION/ORDERING INFORMATION

The AUP family is TI's premier solution to the industry's low-power needs in battery-powered portable applications. This family ensures a very low static and dynamic power consumption across the entire V_{CC} range of 0.8 V to 3.6 V, resulting in an increased battery life. This product also maintains excellent signal integrity (see Figure 1 and Figure 2).



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet. NanoFree is a trademark of Texas Instruments.



SCES592D-JULY 2004-REVISED DECEMBER 2007

DESCRIPTION/ORDERING INFORMATION (CONTINUED)

This is a single positive-edge-triggered D-type flip-flop. When data at the data (D) input meets the setup time requirement, the data is transferred to the Q output on the positive-going edge of the clock pulse. Clock triggering occurs at a voltage level and is not directly related to the rise time of the clock pulse. Following the hold-time interval, data at the D input can be changed without affecting the levels at the outputs.

NanoFree[™] package technology is a major breakthrough in IC packaging concepts, using the die as the package.

This device is fully specified for partial-power-down applications using I_{off}. The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

ORDERING INFORMATION

| T _A | PACKAGE ⁽¹⁾⁽²⁾ | | ORDERABLE PART NUMBER | TOP-SIDE MARKING ⁽³⁾ |
|----------------|---|--------------|-----------------------|---------------------------------|
| | NanoFree™ – WCSP (DSBGA) 0.23-mm Large Bump – YZP (Pb-free) | Reel of 3000 | SN74AUP1G79YZPR | HW_ |
| | SOT (SOT-23) – DBV | Reel of 3000 | SN74AUP1G79DBVR | H79 |
| –40°C to 85°C | SOT (SOT-23) - DBV | Reel of 250 | SN74AUP1G79DBVT | n/9_ |
| | | Reel of 3000 | SN74AUP1G79DCKR | 1 114/ |
| | SOT (SC-70) – DCK | Reel of 250 | SN74AUP1G79DCKT | HW_ |
| | SOT (SOT-553) – DRL | Reel of 4000 | SN74AUP1G79DRLR | HW_ |

(1) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.

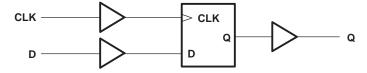
(2) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.

(3) DBV/DCK/DRL: The actual top-side marking has one additional character that designates the assembly/test site. YZP: The actual top-side marking has three preceding characters to denote year, month, and sequence code, and one following character to designate the assembly/test site. Pin 1 identifier indicates solder-bump composition(1 = SnPb, • = Pb-free).

| INPU | TS | OUTPUT |
|--------|----|----------------|
| CLK | D | Q |
| 1 | Н | Н |
| ↑ | L | L |
| L or H | Х | Q ₀ |

FUNCTION TABLE

LOGIC DIAGRAM (POSITIVE LOGIC)





Absolute Maximum Ratings⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

| | | | MIN | MAX | UNIT |
|------------------|--|---|------|-----|------|
| V _{CC} | Supply voltage range | | -0.5 | 4.6 | V |
| VI | Input voltage range ⁽²⁾ | | -0.5 | 4.6 | V |
| Vo | Voltage range applied to any output in the high-ir | Voltage range applied to any output in the high-impedance or power-off state ⁽²⁾ | | | |
| Vo | Output voltage range in the high or low state ⁽²⁾ | | | | V |
| I _{IK} | Input clamp current | V ₁ < 0 | | -50 | mA |
| I _{OK} | Output clamp current | V _O < 0 | | -50 | mA |
| I _O | Continuous output current | | | ±20 | mA |
| | Continuous current through V_{CC} or GND | | ±50 | mA | |
| | | DBV package | | 206 | |
| 0 | Package thermal impedance ⁽³⁾ | DCK package | | 252 | °C/W |
| θ_{JA} | Package mermai impedance. | DRL package | | 142 | |
| | | YZP package | | 132 | |
| T _{stg} | Storage temperature range | | -65 | 150 | °C |

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

(3) The package thermal impedance is calculated in accordance with JESD 51-7.

SCES592D-JULY 2004-REVISED DECEMBER 2007



Recommended Operating Conditions⁽¹⁾

| | | | MIN | MAX | UNIT |
|--------------------------------|------------------------------------|---|---------------------|---------------------|------|
| V _{CC} | Supply voltage | | 0.8 | 3.6 | V |
| | | V _{CC} = 0.8 V | V _{CC} | | |
| V | | $V_{CC} = 1.1 \text{ V to } 1.95 \text{ V}$ | $0.65 	imes V_{CC}$ | | V |
| V _{IH} | High-level input voltage | V_{CC} = 2.3 V to 2.7 V | 1.6 | | v |
| | | $V_{CC} = 3 V$ to 3.6 V | 2 | | |
| | | V _{CC} = 0.8 V | | 0 | |
| | | $V_{CC} = 1.1 \text{ V to } 1.95 \text{ V}$ | | $0.35 	imes V_{CC}$ | V |
| V _{IL} | Low-level input voltage | $V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$ | | 0.7 | V |
| | | $V_{CC} = 3 V$ to 3.6 V | | 0.9 | |
| VI | Input voltage | | 0 | 3.6 | V |
| Vo | Output voltage | | 0 | V _{CC} | V |
| | | V _{CC} = 0.8 V | | -20 | μA |
| | High-level output current | V _{CC} = 1.1 V | | -1.1 | |
| . (2) | | $V_{CC} = 1.4 V$ | | -1.7 | |
| I _{OH} ⁽²⁾ | | V _{CC} = 1.65 V | | -1.9 | mA |
| | | $V_{CC} = 2.3 V$ | | -3.1 | |
| | | $V_{CC} = 3 V$ | | -4 | |
| | | V _{CC} = 0.8 V | | 20 | μΑ |
| | | V _{CC} = 1.1 V | | 1.1 | |
| ı (2) | | $V_{CC} = 1.4 V$ | | 1.7 | |
| I _{OL} ⁽²⁾ | Low-level output current | V _{CC} = 1.65 V | 1.9 | | mA |
| | | V _{CC} = 2.3 V | | 3.1 | |
| | | $V_{CC} = 3 V$ | | 4 | |
| Δt/Δv | Input transition rise or fall rate | $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$ | | 200 | ns/V |
| T _A | Operating free-air temperature | | -40 | 85 | °C |

All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inuts*, literature number SCBA004. Defined by the signal integrity requirements and design-goal priorities (1)

(2)



Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

| DADAMETER | | | v | T, | ₄ = 25°C | T _A = −40°C to 85°C | | | |
|-----------------------|---|-------------|-----------------|-----------------------|--------------------|--------------------------------|------|--|-----|
| PARAMETER | TEST CONDITIONS | • | V _{cc} | MIN | TYP MAX | MIN MAX | UNIT | | |
| | I _{OH} = -20 μA | | 0.8 V to 3.6 V | V _{CC} - 0.1 | | V _{CC} – 0.1 | | | |
| | I _{OH} = -1.1 mA | | 1.1 V | $0.75 	imes V_{CC}$ | | $0.7 \times V_{CC}$ | | | |
| | I _{OH} = -1.7 mA | | 1.4 V | 1.11 | | 1.03 | | | |
| M | I _{OH} = -1.9 mA | | 1.65 V | 1.32 | | 1.3 | V | | |
| V _{OH} | I _{OH} = -2.3 mA | | 2.2.1/ | 2.05 | | 1.97 | V | | |
| | I _{OH} = -3.1 mA | | 2.3 V | 1.9 | | 1.85 | | | |
| | I _{OH} = -2.7 mA | | 3 V | 2.72 | | 2.67 | | | |
| | $I_{OH} = -4 \text{ mA}$ | | 3 V | 2.6 | | 2.55 | | | |
| | I _{OL} = 20 μA | | 0.8 V to 3.6 V | | 0.1 | 0.1 | | | |
| | I _{OL} = 1.1 mA | | 1.1 V | | $0.3 	imes V_{CC}$ | $0.3 	imes V_{CC}$ | | | |
| | I _{OL} = 1.7 mA | | 1.4 V | | 0.31 | 0.37 | | | |
| M | I _{OL} = 1.9 mA | | 1.65 V | | 0.31 | 0.35 | V | | |
| V _{OL} | I _{OL} = 2.3 mA | | 2.3 V | | 0.31 | 0.33 | V | | |
| | I _{OL} = 3.1 mA | | 2.3 V | | 0.44 | 0.45 | | | |
| | I _{OL} = 2.7 mA | | 2.1/ | | 0.31 | 0.33 | | | |
| | $I_{OL} = 4 \text{ mA}$ | | 3 V | | 0.44 | 0.45 | | | |
| II D or CLK input | $V_I = GND$ to 3.6 V | | 0 V to 3.6 V | | 0.1 | 0.5 | μA | | |
| l _{off} | V_{I} or V_{O} = 0 V to 3.6 V | | 0 V | | 0.2 | 0.6 | μΑ | | |
| ΔI _{of} f | $V_{I} \text{ or } V_{O} = 0 \text{ V to } 3.6 \text{ V}$ | | 0 V to 0.2 V | | 0.2 | 0.6 | μA | | |
| I _{CC} | $V_I = GND \text{ or } V_{CC} \text{ to } 3.6 \text{ V},$ | $I_{O} = 0$ | 0.8 V to 3.6 V | | 0.5 | 0.9 | μA | | |
| ΔI _C c | $V_{I} = V_{CC} - 0.6 V^{(1)}$ | $I_{O} = 0$ | 3.3 V | | 40 | 50 | μA | | |
| | | | | | 0 V | 1.5 | | | ~ Г |
| Ci | $V_I = V_{CC}$ or GND | 3.6 V | | 1.5 | | pF | | | |
| Co | V _O = GND | | 0 V | | 3 | | pF | | |

(1) One-input switching



SCES592D-JULY 2004-REVISED DECEMBER 2007

Timing Requirements

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 3)

| | | | V _{cc} | T _A = 25°C | T _A = −40°C to 85°C | UNIT |
|--------------------|---------------------------------|-----------|-----------------|-----------------------|-----------------------------------|------|
| | | | | TYP | MIN MAX | |
| | | | 0.8 V | | 20 | |
| | | | 1.2 V ± 0.1 V | | 80 | |
| | | | 1.5 V ± 0.1 V | | 100 | |
| f _{clock} | Clock frequency | | 1.8 V ± 0.15 V | | 140 | MHz |
| | | | 2.5 V ± 0.2 V | | 210 | |
| | | | 3.3 V ± 0.3 V | | 260 | |
| | | | 0.8 V | | 4.8 | |
| | | | 1.2 V ± 0.1 V | | 2.2 | |
| | Dulas duration OLK bish on loss | | 1.5 V ± 0.1 V | | 1.5 | |
| t _w | Pulse duration, CLK high or low | | 1.8 V ± 0.15 V | | 1.6 | ns |
| | | | 2.5 V ± 0.2 V | | 1.7 | |
| | | | 3.3 V ± 0.3 V | | 1.9 | |
| | | | 0.8 V | 2.9 | 4.2 | |
| | | | 1.2 V ± 0.1 V | | 1.4 | |
| | | | 1.5 V ± 0.1 V | | 1 | |
| | | Data high | 1.8 V ± 0.15 V | | 0.9 | + |
| | | | 2.5 V ± 0.2 V | | 0.7 | |
| | | | 3.3 V ± 0.3 V | | 0.6 | |
| t _{su} | Setup time before CLK↑ | | 0.8 V | 3.5 | 5.3 | ns |
| | | | 1.2 V ± 0.1 V | | 1.8 | |
| | | | 1.5 V ± 0.1 V | | 1.2 | |
| | | Data low | 1.8 V ± 0.15 V | | 1.1 | |
| | | | 2.5 V ± 0.2 V | | 1 | |
| | | | 3.3 V ± 0.3 V | | 1 | |
| | | I | 0.8 V | 0 | 0 | |
| | | | 1.2 V ± 0.1 V | | 0 | |
| | | | 1.5 V ± 0.1 V | | 0 | |
| t _h | Hold time, data after CLK↑ | | 1.8 V ± 0.15 V | | 0 | ns |
| | | | | | 0 | 1 |
| | | | | | 0 | |



Switching Characteristics

over recommended operating free-air temperature range, $C_L = 5 \text{ pF}$ (unless otherwise noted) (see Figure 3 and Figure 4)

| PARAMETER | FROM TO (INPUT) (OUTPUT) | | V _{cc} | T _A = 25°C | | | T _A = −40°C to 85°C | | UNIT |
|------------------|-----------------------------|----------|-----------------|-----------------------|------|-----|-----------------------------------|------|-------|
| | | (001201) | | MIN | TYP | MAX | MIN | MAX | |
| | | | 0.8 V | | 93 | | 90 | | |
| | | | 1.2 V ± 0.1 V | | 199 | | 220 | | |
| 4 | | | 1.5 V ± 0.1 V | | 250 | | 230 | | MHz |
| f _{max} | | | 1.8 V ± 0.15 V | | 271 | | 240 | | IVITZ |
| | | | 2.5 V ± 0.2 V | | 280 | | 250 | | |
| | | | 3.3 V ± 0.3 V | | 280 | | 260 | | |
| | | | 0.8 V | | 15.9 | | | | |
| | | | 1.2 V ± 0.1 V | 3.7 | 6.9 | 11 | 2.6 | 13.1 | |
| | CLK | 0 | 1.5 V ± 0.1 V | 3 | 4.8 | 7.6 | 2 | 8.8 | ~ ~ |
| t _{pd} | CLK | Q | 1.8 V ± 0.15 V | 2.4 | 3.8 | 6.1 | 1.5 | 7.1 | ns |
| | | | 2.5 V ± 0.2 V | 1.8 | 2.7 | 4.4 | 1.1 | 5 | |
| | | | 3.3 V ± 0.3 V | 1.5 | 2.1 | 3.6 | 0.9 | 4 | |

Switching Characteristics

over recommended operating free-air temperature range, $C_L = 10 \text{ pF}$ (unless otherwise noted) (see Figure 3 and Figure 4)

| PARAMETER | FROM | | V _{cc} | T _A = 25°C | | | T _A = −40°C to 85°C | | UNIT |
|------------------|--------------|----------|--------------------------|-----------------------|-----|------|-----------------------------------|------|-------|
| | (INPUT) (OUT | (001901) | (OUTPUT) V _{CC} | MIN | TYP | MAX | MIN | MAX | |
| | | | 0.8 V | | 62 | | 50 | | |
| | | | 1.2 V ± 0.1 V | | 147 | | 160 | | |
| f | | | 1.5 V ± 0.1 V | | 189 | | 200 | | MHz |
| f _{max} | | | 1.8 V ± 0.15 V | | 180 | | 240 | | IVIEZ |
| | | | 2.5 V ± 0.2 V | | 260 | | 250 | | |
| | | | 3.3 V ± 0.3 V | | 280 | | 260 | | |
| | | | 0.8 V | | 18 | | | | |
| | | | 1.2 V ± 0.1 V | 4.3 | 7.8 | 12.3 | 3.2 | 14.4 | |
| + | | 0 | 1.5 V ± 0.1 V | 3.5 | 5.5 | 8.4 | 2.5 | 9.8 | |
| t _{pd} | CLK | Q | 1.8 V ± 0.15 V | 2.8 | 4.4 | 6.8 | 1.9 | 8 | ns |
| | | | 2.5 V ± 0.2 V | 2.2 | 3.2 | 5 | 1.5 | 5.7 | |
| | | | 3.3 V ± 0.3 V | 1.8 | 2.6 | 4.1 | 1.3 | 4.5 | |





Switching Characteristics

over recommended operating free-air temperature range, $C_L = 15 \text{ pF}$ (unless otherwise noted) (see Figure 3 and Figure 4)

| PARAMETER | FROM | | V _{cc} | T _A = 25°C | | | T _A = −40°C to 85°C | | UNIT |
|------------------|---------|----------|-----------------|-----------------------|------|------|-----------------------------------|------|-------|
| | (INPUT) | (001201) | | MIN | TYP | MAX | MIN | MAX | |
| | | | 0.8 V | | 48 | | 30 | | |
| | | | 1.2 V ± 0.1 V | | 112 | | 120 | | |
| 4 | | | 1.5 V ± 0.1 V | | 151 | | 160 | | MHz |
| f _{max} | | | 1.8 V ± 0.15 V | | 194 | | 220 | | IVITZ |
| | | | 2.5 V ± 0.2 V | | 248 | | 250 | | |
| | | | 3.3 V ± 0.3 V | | 280 | | 260 | | |
| | | | 0.8 V | | 20.3 | | | | |
| | | | 1.2 V ± 0.1 V | 5 | 8.7 | 13.6 | 3.9 | 15.6 | |
| | | 0 | 1.5 V ± 0.1 V | 4.1 | 6.3 | 9.3 | 3.1 | 10.7 | 20 |
| t _{pd} | CLK | Q | 1.8 V ± 0.15 V | 3.3 | 4 | 7.6 | 2.4 | 8.7 | ns |
| | | | 2.5 V ± 0.2 V | 2.6 | 3.6 | 5.5 | 1.9 | 6.3 | |
| | | | 3.3 V ± 0.3 V | 2.2 | 3 | 4.5 | 1.6 | 5 | |

Switching Characteristics

over recommended operating free-air temperature range, C_L = 30 pF (unless otherwise noted) (see Figure 3 and Figure 4)

| PARAMETER | FROM | TO (OUTPUT) | V _{cc} | T _A = 25°C | | | T _A = −40°C to 85°C | | UNIT |
|------------------|---------|----------------|-----------------|-----------------------|------|------|-----------------------------------|------|--------|
| | (INPUT) | (001201) | | MIN | TYP | MAX | MIN | MAX | |
| | | | 0.8 V | | 24 | | 20 | | |
| | | | 1.2 V ± 0.1 V | | 72 | | 80 | | |
| £ | | | 1.5 V ± 0.1 V | | 100 | | 100 | | MHz |
| f _{max} | | | 1.8 V ± 0.15 V | | 127 | | 140 | | IVITIZ |
| | | | 2.5 V ± 0.2 V | | 185 | | 210 | | |
| | | | 3.3 V ± 0.3 V | | 266 | | 260 | | |
| | | | 0.8 V | | 27.2 | | | | |
| | | | 1.2 V ± 0.1 V | 7 | 11.5 | 17.3 | 5.9 | 24 | |
| | CLK | 0 | 1.5 V ± 0.1 V | 5.7 | 8.3 | 11.8 | 4.6 | 15.9 | 20 |
| t _{pd} | CLK | CLK Q | 1.8 V ± 0.15 V | 4.7 | 6.7 | 9.6 | 3.8 | 13 | ns |
| | | | 2.5 V ± 0.2 V | 3.7 | 4.9 | 7 | 2.9 | 9 | |
| | | | 3.3 V ± 0.3 V | 3.2 | 4.1 | 5.8 | 2.6 | 7.2 | |

Operating Characteristics

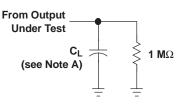
 $T_A = 25^{\circ}C$

| | PARAMETER | TEST CONDITIONS | V _{cc} | TYP | UNIT |
|-----------------|-------------------------------|-----------------|-----------------|-----|------------|
| | | | 0.8 V | 2.5 | |
| | | | 1.2 V ± 0.1 V | 2.5 | |
| ~ | Dower dissinction consultance | f = 10 MHz | 1.5 V ± 0.1 V | 2.5 | ~ F |
| C _{pd} | Power dissipation capacitance | | 1.8 V ± 0.15 V | 2.5 | pF |
| | | | 2.5 V ± 0.2 V | 3 | |
| | | | 3.3 V ± 0.3 V | 3 | |



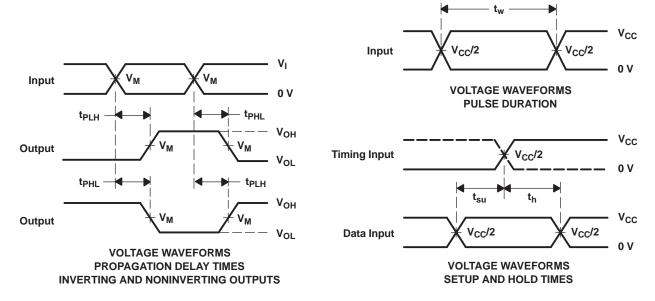
SCES592D-JULY 2004-REVISED DECEMBER 2007

PARAMETER MEASUREMENT INFORMATION (Propagation Delays, Setup and Hold Times, and Pulse Width)



LOAD CIRCUIT

| | V _{CC} = 0.8 V | V _{CC} = 1.2 V ± 0.1 V | V _{CC} = 1.5 V ± 0.1 V | V _{CC} = 1.8 V ± 0.15 V | V_{CC} = 2.5 V \pm 0.2 V | $\begin{array}{c} V_{CC} \texttt{=} \texttt{3.3 V} \\ \pm \texttt{0.3 V} \end{array}$ |
|----------------|-------------------------|------------------------------------|------------------------------------|-------------------------------------|---------------------------------|---|
| CL | 5, 10, 15, 30 pF | 5, 10, 15, 30 pF | 5, 10, 15, 30 pF | 5, 10, 15, 30 pF | 5, 10, 15, 30 pF | 5, 10, 15, 30 pF |
| V _M | V _{CC} /2 | V _{CC} /2 | V _{CC} /2 | V _{CC} /2 | V _{CC} /2 | V _{CC} /2 |
| VI | V _{CC} | V _{CC} | V _{CC} | V _{CC} | V _{CC} | V _{CC} |



NOTES: A. C_L includes probe and jig capacitance.

B. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_O = 50 Ω , t_r/t_f = 3 ns.

C. The outputs are measured one at a time, with one transition per measurement.

- D. t_{PLH} and t_{PHL} are the same as t_{pd} .
- E. All parameters and waveforms are not applicable to all devices.

Figure 3. Load Circuit and Voltage Waveforms

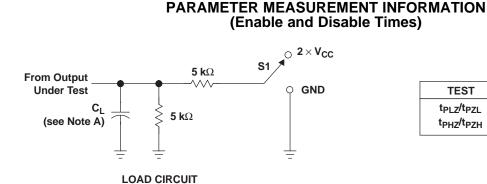


S1

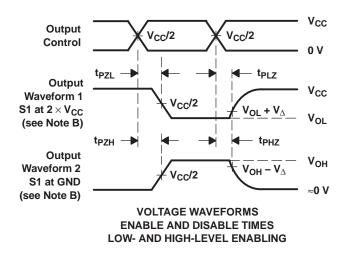
 $2 \times V_{CC}$

GND

SCES592D-JULY 2004-REVISED DECEMBER 2007



| | V _{CC} = 0.8 V | V _{CC} = 1.2 V ± 0.1 V | V _{CC} = 1.5 V ± 0.1 V | V _{CC} = 1.8 V ± 0.15 V | V _{CC} = 2.5 V ± 0.2 V | V _{CC} = 3.3 V ± 0.3 V |
|----------------|-------------------------|------------------------------------|------------------------------------|-------------------------------------|------------------------------------|------------------------------------|
| | | ± 0.1 v | _ U.I V | ± 0.15 v | _ U.Z V | ± 0.5 ¥ |
| CL | 5, 10, 15, 30 pF | 5, 10, 15, 30 pF | 5, 10, 15, 30 pF | 5, 10, 15, 30 pF | 5, 10, 15, 30 pF | 5, 10, 15, 30 pF |
| V _M | V _{CC} /2 | V _{CC} /2 | V _{CC} /2 | V _{CC} /2 | V _{CC} /2 | V _{CC} /2 |
| VI | V _{CC} | V _{CC} | V _{CC} | V _{CC} | V _{CC} | V _{CC} |
| V_{Λ} | 0.1 V | 0.1 V | 0.1 V | 0.15 V | 0.15 V | 0.3 V |



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
 C. All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, Z_O = 50 Ω, t_r/t_f = 3 ns.
- D. The outputs are measured one at a time, with one transition per measurement.
- D. The outputs are measured one at a time, with one transition per r
- $\begin{array}{lll} {\sf E.} & t_{PLZ} \text{ and } t_{PHZ} \text{ are the same as } t_{dis}. \\ {\sf F.} & t_{PZL} \text{ and } t_{PZH} \text{ are the same as } t_{en}. \end{array}$
- G. All parameters and waveforms are not applicable to all devices.

Figure 4. Load Circuit and Voltage Waveforms

22-Jul-2008

PACKAGING INFORMATION

| Orderable Device | Status ⁽¹⁾ | Package Type | Package Drawing | Pins | Packag Qty | e Eco Plan ⁽²⁾ | Lead/Ball Finisł | n MSL Peak Temp ⁽³⁾ |
|-------------------|-----------------------|-----------------|--------------------|------|---------------|---------------------------|------------------|--------------------------------|
| SN74AUP1G79DBVR | ACTIVE | SOT-23 | DBV | 5 | 3000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| SN74AUP1G79DBVRE4 | ACTIVE | SOT-23 | DBV | 5 | 3000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| SN74AUP1G79DBVRG4 | ACTIVE | SOT-23 | DBV | 5 | 3000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| SN74AUP1G79DBVT | ACTIVE | SOT-23 | DBV | 5 | 250 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| SN74AUP1G79DBVTE4 | ACTIVE | SOT-23 | DBV | 5 | 250 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| SN74AUP1G79DBVTG4 | ACTIVE | SOT-23 | DBV | 5 | 250 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| SN74AUP1G79DCKR | ACTIVE | SC70 | DCK | 5 | 3000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| SN74AUP1G79DCKRE4 | ACTIVE | SC70 | DCK | 5 | 3000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| SN74AUP1G79DCKRG4 | ACTIVE | SC70 | DCK | 5 | 3000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| SN74AUP1G79DCKT | ACTIVE | SC70 | DCK | 5 | 250 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| SN74AUP1G79DCKTE4 | ACTIVE | SC70 | DCK | 5 | 250 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| SN74AUP1G79DCKTG4 | ACTIVE | SC70 | DCK | 5 | 250 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| SN74AUP1G79DRLR | ACTIVE | SOT | DRL | 5 | 4000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| SN74AUP1G79DRLRG4 | ACTIVE | SOT | DRL | 5 | 4000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| SN74AUP1G79YZPR | ACTIVE | DSBGA | YZP | 5 | 3000 | Green (RoHS & no Sb/Br) | SNAGCU | Level-1-260C-UNLIM |

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details. **TBD:** The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

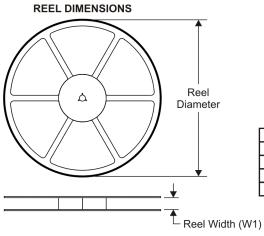
⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

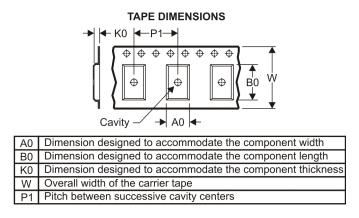


Important Information and Disclaimer:The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

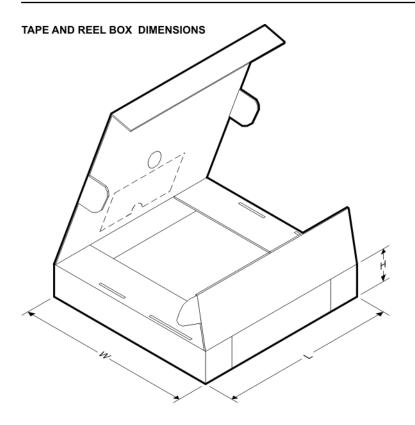


| *All dimensions are nominal | | | | | | | | | | | | |
|-----------------------------|-----------------|--------------------|---|------|--------------------------|--------------------------|---------|---------|---------|------------|-----------|------------------|
| Device | Package Type | Package Drawing | | | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
| SN74AUP1G79DBVR | SOT-23 | DBV | 5 | 3000 | 180.0 | 9.2 | 3.23 | 3.17 | 1.37 | 4.0 | 8.0 | Q3 |
| SN74AUP1G79DBVT | SOT-23 | DBV | 5 | 250 | 180.0 | 9.2 | 3.23 | 3.17 | 1.37 | 4.0 | 8.0 | Q3 |
| SN74AUP1G79DCKR | SC70 | DCK | 5 | 3000 | 180.0 | 9.2 | 2.24 | 2.34 | 1.22 | 4.0 | 8.0 | Q3 |
| SN74AUP1G79DCKT | SC70 | DCK | 5 | 250 | 180.0 | 9.2 | 2.24 | 2.34 | 1.22 | 4.0 | 8.0 | Q3 |
| SN74AUP1G79DRLR | SOT | DRL | 5 | 4000 | 180.0 | 9.2 | 1.78 | 1.78 | 0.69 | 4.0 | 8.0 | Q3 |
| SN74AUP1G79YZPR | DSBGA | YZP | 5 | 3000 | 180.0 | 8.4 | 1.02 | 1.52 | 0.66 | 4.0 | 8.0 | Q1 |



PACKAGE MATERIALS INFORMATION

22-Jul-2008



*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
|-----------------|--------------|-----------------|------|------|-------------|------------|-------------|
| SN74AUP1G79DBVR | SOT-23 | DBV | 5 | 3000 | 202.0 | 201.0 | 28.0 |
| SN74AUP1G79DBVT | SOT-23 | DBV | 5 | 250 | 202.0 | 201.0 | 28.0 |
| SN74AUP1G79DCKR | SC70 | DCK | 5 | 3000 | 202.0 | 201.0 | 28.0 |
| SN74AUP1G79DCKT | SC70 | DCK | 5 | 250 | 202.0 | 201.0 | 28.0 |
| SN74AUP1G79DRLR | SOT | DRL | 5 | 4000 | 202.0 | 201.0 | 28.0 |
| SN74AUP1G79YZPR | DSBGA | YZP | 5 | 3000 | 220.0 | 220.0 | 34.0 |

DBV (R-PDSO-G5)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.

D. Falls within JEDEC MO-178 Variation AA.



DCK (R-PDSO-G5)

PLASTIC SMALL-OUTLINE PACKAGE



- NOTES: A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
 - D. Falls within JEDEC MO-203 variation AA.



DRL (R-PDSO-N5)

PLASTIC SMALL OUTLINE



NOTES:

All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994. Α. B. This drawing is subject to change without notice.

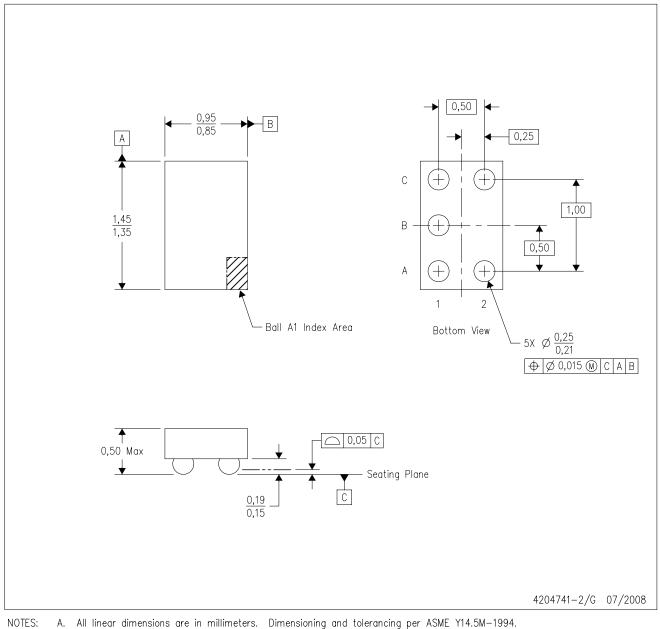
🖄 Body dimensions do not include mold flash, interlead flash, protrusions, or gate burrs. Mold flash, interlead flash, protrusions, or gate burrs shall not exceed 0,15 per end or side.





YZP (R-XBGA-N5)

DIE-SIZE BALL GRID ARRAY



- B. This drawing is subject to change without notice.
- C. NanoFree™ package configuration.
- D. This package is lead-free. Refer to the 5 YEP package (drawing 4204725) for tin-lead (SnPb).

NanoFree is a trademark of Texas Instruments.



IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, modifications, enhancements, improvements, and other changes to its products and services at any time and to discontinue any product or service without notice. Customers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All products are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its hardware products to the specifications applicable at the time of sale in accordance with TI's standard warranty. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by government requirements, testing of all parameters of each product is not necessarily performed.

TI assumes no liability for applications assistance or customer product design. Customers are responsible for their products and applications using TI components. To minimize the risks associated with customer products and applications, customers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any TI patent right, copyright, mask work right, or other TI intellectual property right relating to any combination, machine, or process in which TI products or services are used. Information published by TI regarding third-party products or services does not constitute a license from TI to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. Reproduction of this information with alteration is an unfair and deceptive business practice. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI products or services with statements different from or beyond the parameters stated by TI for that product or service voids all express and any implied warranties for the associated TI product or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

TI products are not authorized for use in safety-critical applications (such as life support) where a failure of the TI product would reasonably be expected to cause severe personal injury or death, unless officers of the parties have executed an agreement specifically governing such use. Buyers represent that they have all necessary expertise in the safety and regulatory ramifications of their applications, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of TI products in such safety-critical applications, notwithstanding any applications-related information or support that may be provided by TI. Further, Buyers must fully indemnify TI and its representatives against any damages arising out of the use of TI products in such safety-critical applications.

TI products are neither designed nor intended for use in military/aerospace applications or environments unless the TI products are specifically designated by TI as military-grade or "enhanced plastic." Only products designated by TI as military-grade meet military specifications. Buyers acknowledge and agree that any such use of TI products which TI has not designated as military-grade is solely at the Buyer's risk, and that they are solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI products are neither designed nor intended for use in automotive applications or environments unless the specific TI products are designated by TI as compliant with ISO/TS 16949 requirements. Buyers acknowledge and agree that, if they use any non-designated products in automotive applications, TI will not be responsible for any failure to meet such requirements.

Following are URLs where you can obtain information on other Texas Instruments products and application solutions:

| Products | | Applications | |
|-----------------------------|------------------------|--------------------|---------------------------|
| Amplifiers | amplifier.ti.com | Audio | www.ti.com/audio |
| Data Converters | dataconverter.ti.com | Automotive | www.ti.com/automotive |
| DSP | dsp.ti.com | Broadband | www.ti.com/broadband |
| Clocks and Timers | www.ti.com/clocks | Digital Control | www.ti.com/digitalcontrol |
| Interface | interface.ti.com | Medical | www.ti.com/medical |
| Logic | logic.ti.com | Military | www.ti.com/military |
| Power Mgmt | power.ti.com | Optical Networking | www.ti.com/opticalnetwork |
| Microcontrollers | microcontroller.ti.com | Security | www.ti.com/security |
| RFID | www.ti-rfid.com | Telephony | www.ti.com/telephony |
| RF/IF and ZigBee® Solutions | www.ti.com/lprf | Video & Imaging | www.ti.com/video |
| | | Wireless | www.ti.com/wireless |

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2008, Texas Instruments Incorporated